

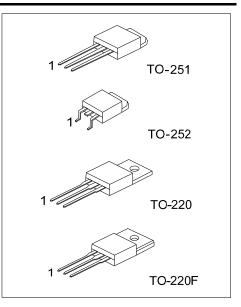
2SA1012

PNP SILICON TRANSISTOR

HIGH CURRENT SWITCHING APPLICATION

FEATURES

*Low Collector Saturation Voltage V_{CE(SAT)}=-0.4V(max.) At Ic=-3A *High Speed Switching Time: $t_S=1.0\mu s(Typ.)$ *Complementary To 2SC2562

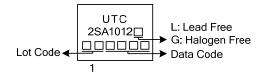


ORDERING INFORMATION

Ordering Number		Packago	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
2SA1012L-x-TA3-T	2SA1012G-x-TA3-T TO-220		В	С	Е	Tube	
2SA1012L-x-TF3-T	2SA1012G-x-TF3-T	TO-220F	В	С	Е	Tube	
2SA1012L-x-TM3-T	2SA1012G-x-TM3-T	TO-251	В	С	Е	Tube	
2SA1012L-x-TN3-R	2SA1012G-x-TN3-R	TO-252	В	С	E	Tape Reel	
Note: Pin Assignment: B: Base C: Collector E: Emitter							
2SA1012L-x-TA3-T	(1) T: Tube, F	•			3· TO_251		

2SA1012L-x-TA3-T (1)Packing Type (2)Package Type	(1) T: Tube, R: Tape Reel (2) TA3: TO-220, TF3: TO-220F, TM3: TO-251, TN3: TO-252	
(3)Rank (4)Green Package	(3) x: reference to Classification of hFE1(4) L: Lead Free, G: Halogen Free and Lead Free	

MARKING



■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V _{CBO}	-60	V
Collector-Emitter Voltage	V _{CEO}	-50	V
Collector-Emitter Voltage	V _{EBO}	-5	V
Peak Collector Current	lc	-5	А
Power Dissipation	PD	25	W
Junction Temperature	TJ	150	°C
Storage Temperature	T _{STG}	-55 ~ +150	°C

Note Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

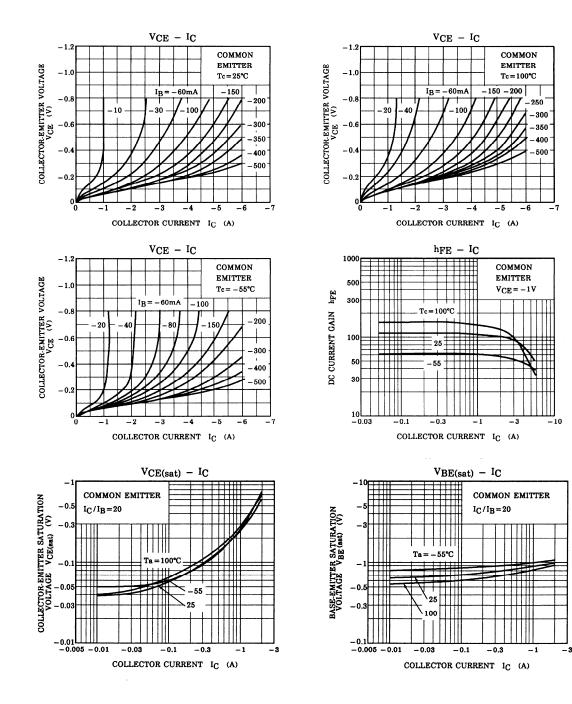
PA	RAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage		BV _{CBO}	I _C =-100μA, I _E =0	-60			V
Collector-Emitte	er Breakdown Voltage	BV_{CEO}	I _C =-10mA, I _B =0	-50			V
Emitter-Base B	reakdown Voltage	BV_{EBO}	I _E =-100μΑ, I _C =0	-5			V
Collector Cut-of	ff Current	I _{CBO}	V _{CB} =-50V, I _E =0			-1.0	μA
Emitter Cut-off	Current	I _{EBO}	V _{EB} =-5V, I _C =0			-1.0	μA
DC Current Gain		h _{FE1}	V _{CE} =-1V, I _C =-1A	70		360	
		h _{FE2}	V _{CE} =-1V, I _C =-3A	30			
Collector-Emitter Saturation Voltage		V _{CE (SAT)}	I _C =-3A, I _B =-0.15A		-0.2	-0.4	V
Base-Emitter Saturation Voltage		V _{BE (SAT)}	I _C =-3A, I _B =-0.15A		-0.9	-1.2	V
Transition frequency		f⊤	V _{CE} =-4V, I _C =-1A		60		MHz
Collector output	t capacitance	Cob	V _{CB} =-10V, I _E =0, f=1MHz		170		pF
Switching time	Turn-on time	t _{on}			0.1		μs
	Storage time	ts			1.0		μs
	Fall time	t _F	$-I_{B1} = I_{B2} = 0.15A$ $DUTY CYCLE \le 2\%$ $V_{CC} = -30V$		0.1		μs

■ CLASSIFICATION of h_{FE1}

RANK	0	Y	R	R1
RANGE	70 ~ 140	120 ~ 240	180 ~ 360	>255

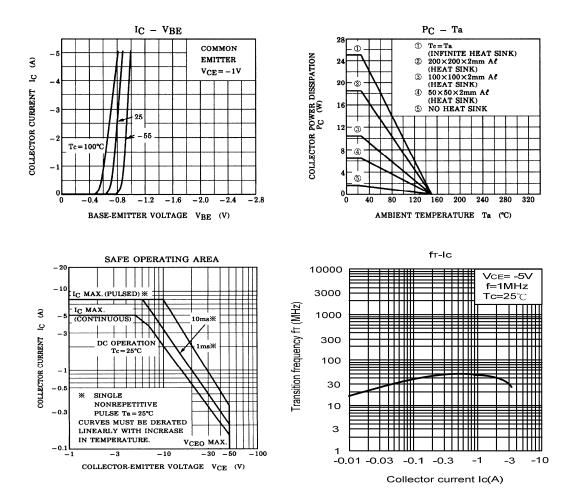


■ TYPICAL CHARACTERISTICS



2SA1012

■ TYPICAL CHARACTERICS (Cont.)



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